		•		
L Number	Hits	Search Text	DB	Time stamp
1	6	(("5306655") or ("5360655") or ("5612249")	USPAT;	2004/09/14 17:59
		or ("5798550") or ("6015736") or	US-PGPUB	
	}	("5637514")).PN.		
2	6	(("5306655") or ("5360758") or ("5612249")	USPAT;	2004/09/14 17:59
		or ("5798550") or ("6015736") or	US-PGPUB	
	_	("5637514")).PN.		2004/00/14 10 30
3	6	(US-5798550-\$ or US-6015736-\$ or   US-5360758-\$ or US-5612249-\$ or	USPAT	2004/09/14 18:39
		US-5637514-\$ or US-5306655-\$).did.		
4	7466		USPAT;	2004/09/14 18:40
•	, 100	(257/344) or (257/368) or (257/401) or	US-PGPUB	2001,03,11 10.10
		(257/408) or (257/410) or (257/411) or		
ĺ		(257/412) or (257/413)).CCLS.		
5	0		USPAT;	2004/09/14 18:42
		(257/344) or (257/368) or (257/401) or	US-PGPUB;	
		(257/408) or (257/410) or (257/411) or	EPO; JPO;	1
1.		(257/412) or (257/413)).CCLS.) and silicon	DERWENT;	
		adj oxide adj passivation adj (layer film) and silicon adj nitride adj spacer and	IBM_TDB	
		gate adj oxide.ti,ab,clm. and "bird's		
		beak"		
6	0	(((257/288) or (257/296) or (257/321) or	USPAT;	2004/09/14 18:42
		(257/344) or (257/368) or (257/401) or	US-PGPUB;	
		(257/408) or (257/410) or (257/411) or	EPO; JPO;	
		(257/412) or (257/413)).CCLS.) and silicon	DERWENT;	
		adj oxide near8 passivation adj (layer	IBM_TDB	.
		film) and silicon adj nitride near8 spacer and gate adj oxide.ti,ab,clm. and "bird's		
		beak"		i l
-	. 5	272,968.ap.	USPAT;	2004/09/14 16:45
	_	\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	US-PGPUB;	2001, 03, 11 10.10
			EPO; JPO;	
			DERWENT;	
		WE 64 00 4 0 W TO	IBM_TDB	
<del>-</del>	1 1	"5612249".PN.	USPAT	2002/05/22 14:58
_	1	"5637514".PN. "5798550".PN.	USPAT USPAT	2002/05/22 14:59 2002/05/22 14:59
_	1	"6015736".PN.	USPAT	2002/05/22 14:39
-	3	("5306655").PN.	USPAT;	2002/05/22 15:43
] ]			US-PGPUB;	
		T.	EPO; JPO;	
			DERWENT;	
	3	("5360758").PN.	IBM_TDB	0000/05/00 17 00
	٥	( 3300/30 ).EN.	USPAT; US-PGPUB;	2002/05/22 17:03
]			EPO; JPO;	
			DERWENT;	
1			IBM_TDB	'.
-	301	((side adj wall or sidewall or side-wall)	USPĀT;	2002/05/23 09:41
		adj spacer near6 nitride) and 257/\$6.ccls.	US-PGPUB;	
		and (field adj effect adj transistor or	EPO; JPO;	
		fet or mos or mos adj fet or mosfet or nmos or pmos or nmosfet or pmosfet)	DERWENT; IBM TDB	
-	3	("5382533").PN.	USPAT;	2002/05/22 17:51
		,	US-PGPUB;	
			EPO; JPO;	
		•	DERWENT;	
	_	/#5 C7 0.0 CO # \ DV	IBM_TDB	
-	3	("5679968").PN.	USPAT;	2002/05/22 17:52
			US-PGPUB; EPO; JPO;	
			DERWENT;	
.	1		IBM TDB	
-	3	("5714413").PN.	USPAT;	2002/05/22 17:53
			US-PGPUB;	. =
			EPO; JPO;	
	ĺ	İ	DERWENT;	
			IBM TDB	

	· · · · · · · · · · · · · · · · · · ·		T	
-	0	("ep-621632\$-\$.did.").PN.	USPAT;	2002/05/22 17:53
			US-PGPUB; EPO; JPO;	
	1		DERWENT;	
			IBM TDB	
-	0	("ep-621632\$-\$.did.").PN.	USPĀT;	2002/05/22 17:53
			US-PGPUB;	
		·	EPO; JPO;	
			DERWENT;	
_	0	rajeevakumar.in. and dram adj cell adj	IBM_TDB EPO	2002/05/22 17:55
		structure	120	2002/03/22 17.33
_	6		USPAT;	2002/05/22 17:55
		structure	US-PGPUB;	
	·		EPO; JPO;	
			DERWENT; IBM TDB	
_	3	("5612249").PN.	USPAT;	2002/05/23 10:42
		( 00==== 7, 1===	US-PGPUB;	2002/03/23 10:12
1			EPO; JPO;	
**			DERWENT;	
1_	0	onem and coloration some translation	IBM_TDB	2002/05/22 22 25
1 -	1	earom and selection same transistor same	USPAT; US-PGPUB;	2002/05/23 10:43
1			EPO; JPO;	
1			DERWENT;	
			IBM_TDB	
-	27	earom and transistor same dram	USPAT;	2002/05/23 10:44
			US-PGPUB;	
1			EPO; JPO; DERWENT;	
· ·	1		IBM TDB	
[ -	6	earom and transistor same dram.ti,ab.	USPAT;	2002/05/23 10:45
			US-PGPUB;	
			EPO; JPO;	
			DERWENT; IBM TDB	
_	109394	earom.ti,ab. and dram.ti,ab. and	USPAT;	2002/05/23 10:46
		257/\$6.ccls. or 438/\$6.ccls.	US-PGPUB;	2002,00,20 10.10
			EPO; JPO;	
			DERWENT;	
_	5	earom.ti,ab. and dram.ti,ab.	IBM_TDB USPAT;	2002/05/23 10:47
		carom.cr, ab. and dram.cr, ab.	US-PGPUB;	2002/03/23 10:47
			EPO; JPO;	
			DERWENT;	
	187	selection nearly /transister f-t	IBM_TDB	2002/05/22 12 15
	10/	selection near12 (transistor or fet or mosfet) near12 dram	USPAT; US-PGPUB;	2002/05/23 10:49
			EPO; JPO;	
			DERWENT;	
		-	IBM_TDB	
<del>-</del>	44	(selection near6 (transistor or fet or	USPAT;	2002/05/23 12:09
		mosfet) near6 dram) and (257/\$6.ccls. or 438/\$6.ccls.)	US-PGPUB; EPO; JPO;	
		, ,,	DERWENT;	
			IBM_TDB	
-	3	("5854500").PN.	USPĀT;	2002/05/23 12:14
			US-PGPUB;	
			EPO; JPO; DERWENT;	
			IBM TDB	
-	2	("6037639").PN.	USPAT;	2002/05/23 13:57
			US-PGPUB;	
1			EPO; JPO;	
			DERWENT; IBM TDB	
-	1962	(257/296).CCLS.	USPAT;	2002/05/23 12:26
į			US-PGPUB;	11=,10,20 12.20
			EPO; JPO;	
			DERWENT;	
			IBM TDB	

			· · · · · · · · · · · · · · · · · · ·	1
-	1041	(257/401).CCLS.	USPAT;	2002/05/23 15:08
			US-PGPUB;	
			EPO; JPO; DERWENT;	
			IBM TDB	
_	432	(257/410).CCLS.	USPAT;	2002/05/23 15:08
		(231, 123, 133231	US-PGPUB;	2002, 00, 20 10, 00
			EPO; JPO;	1
			DERWENT;	
			IBM TDB	
-	2	("5885553").PN.	USPAT;	2002/11/06 10:35
			US-PGPUB;	
	,	·	EPO; JPO;	1
			DERWENT;	
		485 C1 00 40 B1	IBM_TDB	
-	2	("5612249").PN.	USPAT;	2002/11/06 12:04
			US-PGPUB;	
			EPO; JPO;	
			DERWENT; IBM TDB	
1_	1 0	(side adj wall or sidewall) near12 gate	USPAT;	2002/11/06 12:06
		adj oxide near12 silicon adj nitride adj	US-PGPUB;	2002/11/00 12:00
	1	spacer	EPO; JPO;	
			DERWENT;	
	1	·	IBM TDB	
-	. 15		USPAT;	2002/11/06 12:07
	[	adj oxide near12 silicon adj nitride	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
,	İ		IBM_TDB	
-	147	oxidation adj barrier near4 oxide	USPAT;	2002/11/06 13:06
			US-PGPUB;	
	İ		EPO; JPO;	
			DERWENT;	
l _	201	(MOS on MOSERE) ti ab alm and ailine adi	IBM_TDB	0000/11/06 12 00
	201	(MOS or MOSFET).ti,ab,clm. and silicon adj nitride near4 (sidewall or side adj wall)	USPAT; US-PGPUB;	2002/11/06 13:09
		near4 spacer	EPO; JPO;	
		near4 spacer	DERWENT;	
			IBM TDB	
-	3702	((257/296) or (257/401) or	USPAT;	2002/11/06 16:38
		(257/410)).CCLS.	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	0	(((257/296) or (257/401) or	USPĀT;	2002/11/06 16:39
		(257/410)).CCLS.) and "bird's beak" near4	US-PGPUB;	
		gate near4 underneath and silicon adj	EPO; JPO;	
		nitride	DERWENT;	
_	2	("5612249").PN.	IBM_TDB	2002/04/15 14:10
		( JULZZEJ ).FN.	USPAT; US-PGPUB;	2003/04/15 14:10
	•		EPO; JPO;	
	i		DERWENT;	
			IBM TDB	
	259	oxide near2 spacer near6 nitride and	USPAT;	2003/04/15 14:15
	i	(mosfet or mos adj device or field adj	US-PGPUB;	111, 11, 10 11, 10
]		effect adj transistor).ti,ab,clm.	EPO; JPO;	
			DERWENT;	
			IBM_TDB	•
-	6	885553.ap.	USPĀT;	2003/10/08 10:23
			US-PGPUB;	
			EPO; JPO;	
		•	DERWENT;	
i _	2	("5612249").PN.	IBM_TDB	0000 (10 (00 10 6)
	۷	\ JUIZZES /.FN.	USPAT;	2003/10/08 10:24
			US-PGPUB; EPO; JPO;	
			DERWENT;	
			IBM TDB	
<u> </u>			ביטיד	

-	. 2	("5907777").PN.	USPAT;	2003/10/08 11:43
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
1_	4300	((257/296) or (257/401) or	IBM_TDB USPAT;	2003/10/08 11:44
-	4300	((257/296) 61 (257/461) 61 ((257/410)).CCLS.	US-PGPUB;	2003/10/08 11:44
		(237/410/).ccbs.	EPO; JPO;	
			DERWENT;	
			IBM TDB	1
_	8	(((257/296) or (257/401) or	USPĀT;	2003/10/08 11:44
		(257/410)).CCLS.) and "bird's beak"	US-PGPUB;	2000, 20, 00 22111
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
-	6	885553.ap.	USPAT;	2004/09/13 16:40
		-	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	30	(US-5854500-\$ or US-5880496-\$ or	USPAT;	2004/09/13 16:52
		US-5969382-\$ or US-6121651-\$ or	US-PGPUB;	
		US-4610078-\$ or US-5473179-\$ or	JPO	
		US-5939761-\$ or US-6025215-\$ or		
		US-5907777-\$ or US-5923965-\$ or		
		US-6114735-\$ or US-6127710-\$ or		
		US-5637514-\$ or US-5306655-\$ or		
		US-5360758-\$ or US-6015736-\$ or		
		US-5798550-\$ or US-5612249-\$ or		
		US-6281079-\$ or US-6180978-\$ or US-6037639-\$ or US-5929492-\$ or		
		US-5382533-\$ or US-5714413-\$ or		
		US-5679968-\$ or US-5706164-\$).did. or	1	
		(US-20030042551-\$ or US-20010041398-\$ or		
		US-20010033006-\$).did. or		
		(JP-05129595-\$).did.		_
	3	((US-5854500-\$ or US-5880496-\$ or	USPAT;	2004/09/13 16:52
. [		US-5969382-\$ or US-6121651-\$ or	US-PGPUB;	
	1	US-4610078-\$ or US-5473179-\$ or	EPO; JPO;	
		US-5939761-\$ or US-6025215-\$ or	DERWENT;	
		US-5907777-\$ or US-5923965-\$ or	IBM TDB	
		US-6114735-\$ or US-6127710-\$ or		
		US-5637514-\$ or US-5306655-\$ or		
		US-5360758-\$ or US-6015736-\$ or		
		US-5798550-\$ or US-5612249-\$ or		
	İ	US-6281079-\$ or US-6180978-\$ or		
		US-6037639-\$ or US-5929492-\$ or		
		US-5382533-\$ or US-5714413-\$ or		
		US-5679968-\$ or US-5706164-\$).did. or		
	1	(US-20030042551-\$ or US-20010041398-\$ or		
[	İ	US-20010033006-\$).did. or		
	_	(JP-05129595-\$).did.) and ahmad.in.		
-	6	272968.ap.	USPAT;	2004/09/14 17:56
]			US-PGPUB;	
	Ì		EPO; JPO;	
			DERWENT;	
_	1		IBM_TDB	2004/00/14 16 :5
L			USPAT	2004/09/14 16:48